	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	340471	(fet or transistor or gate) and ((("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:54			
2	BRS	L2	248723	(fet or transistor or gate) same ((("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:12			
3	BRS	L3	110341	(fet or transistor or gate) and ((first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (first and second) same (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:13			
4	BRS	L4	67503	(fet or transistor or gate) same ((first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (first and second) same (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:14			
5	BRS	L5	110341	(fet or transistor or gate) and ((deposit$3 or form$3) same (first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (first and second) same (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:15			
6	BRS	L6	67503	(fet or transistor or gate) same ((deposit$3 or form$3) same (first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (first and second) same (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:15			
7	BRS	L7	67503	(fet or transistor or gate) same ((deposit$3 or form$3) same (first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or ((first and second) same (silicon oxide or "SiO.sub.2" or SiO2 or TEOS)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:17			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
8	BRS	L8	110341	(fet or transistor or gate) and ((((deposit$3 or form$3) same (first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped))) or ((first and second) same (silicon oxide or "SiO.sub.2" or SiO2 or TEOS)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:19			
9	BRS	L9	67503	(fet or transistor or gate) same ((((deposit$3 or form$3) same (first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped))) or ((first and second) same (silicon oxide or "SiO.sub.2" or SiO2 or TEOS)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:21			
10	BRS	L10	13252	(fet or transistor or gate) same ((((deposit$3 or form$3) same (first and second) same (("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped))) or ((first and second) same ("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:24			
11	BRS	L11	5030	10 and @pd<="20000320"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:25			
12	BRS	L12	2143	11 and "438"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:25			
13	BRS	L13	10587	10 and (dop$3 or implant$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:26			
14	BRS	L14	3631	13 and @pd<="20000320"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:26			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
15	BRS	L15	1798	14 and "438"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 11:26			
16	BRS	L16	9949	10 and (dop$3 or implant$5)	US-PGPUB; USPAT; USOCR	2005/09/16 13:56			
17	BRS	L17	3143	16 and @pd<="20000320"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:56			
18	BRS	L18	1712	17 and "438"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:50			
19	BRS	L19	0	17 and "H01L021$.IPC"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:53			
20	BRS	L20	0	16 and "H01L021$.IPC"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:53			
21	BRS	L21	10587	10 and (dop$3 or implant$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:53			
22	BRS	L22	0	21 and "H01L021$.IPC"	EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:54			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
23	BRS	L23	273929	(dram or gate) and ((("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:55			
24	BRS	L24	189220	(dram or gate) same ((("silicon oxide" or "SiO.sub.2" or SiO2 or TEOS or oxide) adj3 (undoped)) or (silicon oxide or "SiO.sub.2" or SiO2 or TEOS))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:55		.	
25	BRS	L25	73199	24 and (dop$3 or implant$5)	US-PGPUB; USPAT; USOCR	2005/09/16 13:56			
26	BRS	L26	24695	25 and @pd<="20000320"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 15:46			.
27	BRS	L27	818	SANDHU-GURTEJ-S.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 13:58			
28	BRS	L28	2988	(TEOS same ("silicon oxide" or "SiO.sub.2" or SiO2)) same (gate or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 15:44			
29	BRS	L29	69434	(dop$3 or implant$5 or (ion implant$5)) same ("silicon oxide" or "SiO.sub.2" or SiO2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 15:46			.
30	BRS	L30	1830	28 and 29	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 15:47			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
31	BRS	L31	508	30 and @pd<="20000320"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 15:47			
32	BRS	L32	910	28 same 29	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 15:47			
33	BRS	L33	307	32 and @pd<="20000320"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 16:18			
34	BRS	L34	0	33 not 32	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 16:19			
35	BRS	L35	603	32 not 33	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/09/16 16:19			